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SuperFET<sup>®</sup> MOSFET is Fairchild Semiconductor's first genera-

utilizing charge balance technology for outstanding low onresistance and lower gate charge performance. This technology is tailored to minimize conduction loss, provide superior switching performance, dv/dt rate and higher avalanche energy. Consequently, SuperFET MOSFET is very suitable for the switching power applications such as PFC, server/telecom power, FPD TV power, ATX power and industrial power applications. Super-FET FRFET® MOSFET's optimized body diode reverse recovery performance can remove additional component and improve system reliability.

## Description

tion of high voltage super-junction (SJ) MOSFET family that is



FCPF11N60F

## N-Channel SuperFET<sup>®</sup> FRFET<sup>®</sup> MOSFET

600 V, 11 A, 380 mΩ

## Features

- 600 V @ T<sub>J</sub> = 150°C
- Typ. R<sub>DS(on)</sub> = 320 mΩ
- Fast Recovery Type (t<sub>rr</sub> = 120 ns)
- Ultra Low Gate Charge (Typ. Q<sub>g</sub> = 40 nC)
- Low Effective Output Capacitance (Typ. C<sub>oss(eff.)</sub> = 95 pF)
- 100% Avalanche Tested
- · RoHS compliant

## Applications

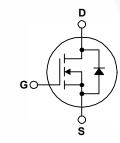
LCD/LED/PDP TV

Lighting

 Solar Inverter · AC-DC Power Supply







## MOSFET Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted.

Symbol		Parameter		FCPF11N60F	Unit	
V <sub>DSS</sub>	Drain to Source Voltage			600	V	
ID	Desia Current	- Continuous (T <sub>C</sub> = 25 <sup>o</sup> C)		11*	•	
	Drain Current	- Continuous (T <sub>C</sub> = 100 <sup>o</sup> C)		7*	— A	
I <sub>DM</sub>	Drain Current	- Pulsed (Note 1)		33*	A	
V <sub>GSS</sub>	Gate to Source Voltage			±30	V	
E <sub>AS</sub>	Single Pulsed Avalanche Energy		(Note 2)	340	mJ	
I <sub>AR</sub>	Avalanche Current		(Note 1)	11	А	
E <sub>AR</sub>	Repetitive Avalanche Energy		(Note 1)	12.5	mJ	
dv/dt	Peak Diode Recovery dv/dt		(Note 3)	4.5	V/ns	
P <sub>D</sub>	Dower Dissinction	(T <sub>C</sub> = 25°C)		36	W	
	Power Dissipation	- Derate Above 25°C		0.29	W/ºC	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range			-55 to +150	°C	
TL	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds			300	°C	

## Thermal Characteristics

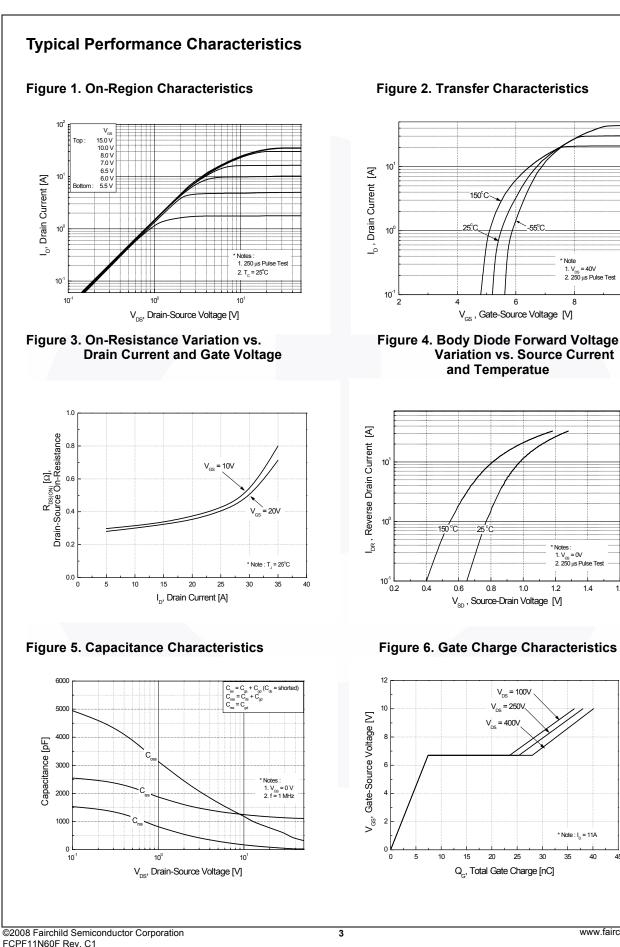
Symbol	Parameter	FCPF11N60F	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	3.5	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient, Max.	62.5	°C/W

Device Marking Device Pac		Pack	age	Reel Size	Таре	e Width		Quantit	у	
FCPF11			TO-2	20F	-		-		50	
Electrica	l Chara	acteristics T <sub>c</sub> =	25 <sup>0</sup> C uplos	se othonw	iso potod					
Symbol		Parameter	25 C unies	ss otherw	Test Conditions		Min.	Тур.	Max.	Unit
, Off Chara	cteristics	5								
				V <sub>CS</sub> =	: 0 V, I <sub>D</sub> = 250 μA, T <sub>C</sub> :	= 25°C	600	-	-	V
BV <sub>DSS</sub>	Drain to	Source Breakdown V	oltage	$V_{GS} = 0 V, I_D = 250 \mu A, T_C = 150^{\circ}C$			-	650	-	V
ΔΒV <sub>DSS</sub> / ΔΤ <sub>J</sub>	Breakdown Voltage Temperature Coefficient		ure	$I_D = 250 \ \mu\text{A}, \ \text{Referenced to } 25^{\circ}\text{C}$			-	0.6	-	V/°C
BV <sub>DS</sub>	Drain-So Voltage	ource Avalanche Brea	Ikdown	V <sub>GS</sub> =	= 0 V, I <sub>D</sub> = 11 A		-	700	-	V
	Zoro Co			V <sub>DS</sub> = 600 V, V <sub>GS</sub> = 0 V		-	-	1		
DSS	zero Ga	ero Gate Voltage Drain Current			480 V, T <sub>C</sub> = 125 <sup>o</sup> C		-	-	10	μA
I <sub>GSS</sub>	Gate to I	Body Leakage Currer	nt	V <sub>GS</sub> =	= ±30 V, V <sub>DS</sub> = 0 V		-	-	±100	nA
On Charao	cteristics	•								
V <sub>GS(th)</sub>		reshold Voltage		V <sub>CS</sub> =	= V <sub>DS</sub> , I <sub>D</sub> = 250 μA		3.0	-	5.0	V
R <sub>DS(on)</sub>		ain to Source On Re	sistance		= 10 V, I <sub>D</sub> = 5.5 A		-	0.32	0.38	Ω
9 <sub>FS</sub>	Forward Transconductance			$V_{DS} = 40 \text{ V}, I_D = 5.5 \text{ A}$			-	6	-	S
Dynamic (	Characte	ristics								
C <sub>iss</sub>		Input Capacitance				-	1148	1490	pF	
C <sub>oss</sub>		Capacitance			V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V, f = 1.0 MHz			671	870	pF
C <sub>rss</sub>	-	Transfer Capacitance	<u>,</u>	f = 1.				63	82	pF
C <sub>oss</sub>		Output Capacitance		V <sub>DS</sub> = 480 V, V <sub>GS</sub> = 0 V, f = 1.0 MHz			-	35	-	pF
C <sub>oss(eff.)</sub>		Effective Output Capacitance		$V_{\rm DS} = 0.000$ V, $V_{\rm GS} = 0.000$ V V V V V V V V V V V V V V V V V V			-	95	-	pF
Q <sub>g(tot)</sub>		te Charge at 10V			= 480 V, I <sub>D</sub> = 11 A,		-	40	52	nC
Q <sub>gs</sub>		Source Gate Charge			= 10 V	_	-	7.2	-	nC
Q <sub>gd</sub>		Drain "Miller" Charge		(Note 4)			-	21	-	nC
Switching										
	-							34	80	
t <sub>d(on)</sub>		Delay Time Rise Time		$V_{DD}$ = 300 V, I <sub>D</sub> = 11 A, R <sub>G</sub> = 25 Ω		-	98	205	ns	
t <sub>r</sub>						-	119	205	ns	
└d(off) +		Delay Time Fall Time					-	56	120	ns
t <sub>f</sub>	Tum-Oil	Fail Time		(Note 4)			-	90	120	ns
Drain-Sou	rce Diod	e Characteristic	S							
I <sub>S</sub>	Maximun	n Continuous Drain to	Source Die	ode Forwa	ard Current		-	-	11	Α
I <sub>SM</sub>	Maximun	n Pulsed Drain to Sou	Irce Diode F	orward C	Current		-	-	33	Α
V <sub>SD</sub>	Drain to :	Source Diode Forwar	d Voltage	V <sub>GS</sub> =	: 0 V, I <sub>SD</sub> = 11 A		-	-	1.4	V
t <sub>rr</sub>	Reverse	Recovery Time	-		= 0 V, I <sub>SD</sub> = 11 A,		-	120		ns
Q <sub>rr</sub>	Reverse	Recovery Charge		dl <sub>F</sub> /dt = 100 A/μs		-	0.8		μC	
lotes:										-
. I <sub>AS</sub> = 5.5 A, V <sub>DI</sub> . I <sub>SD</sub> ≤ 11 A, di/di	<sub>D</sub> = 50 V, R <sub>G</sub> = 2 ≤ 200 A/μs, V <sub>E</sub>	imited by maximum junction 25 $\Omega$ , starting T <sub>J</sub> = 25°C. <sub>DD</sub> $\leq$ BV <sub>DSS</sub> , starting T <sub>J</sub> = 25 erating temperature.								

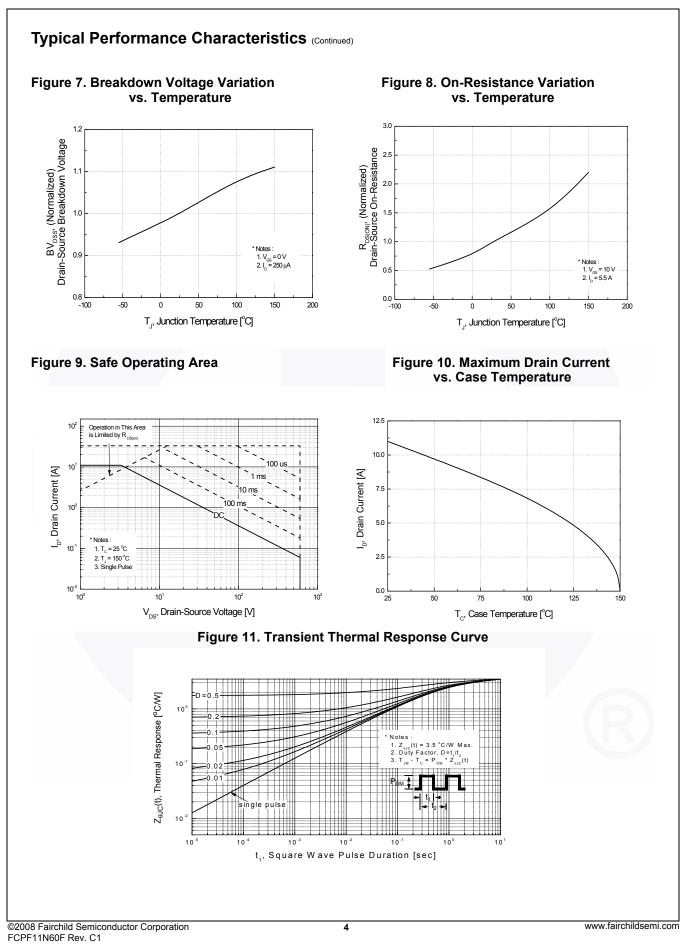
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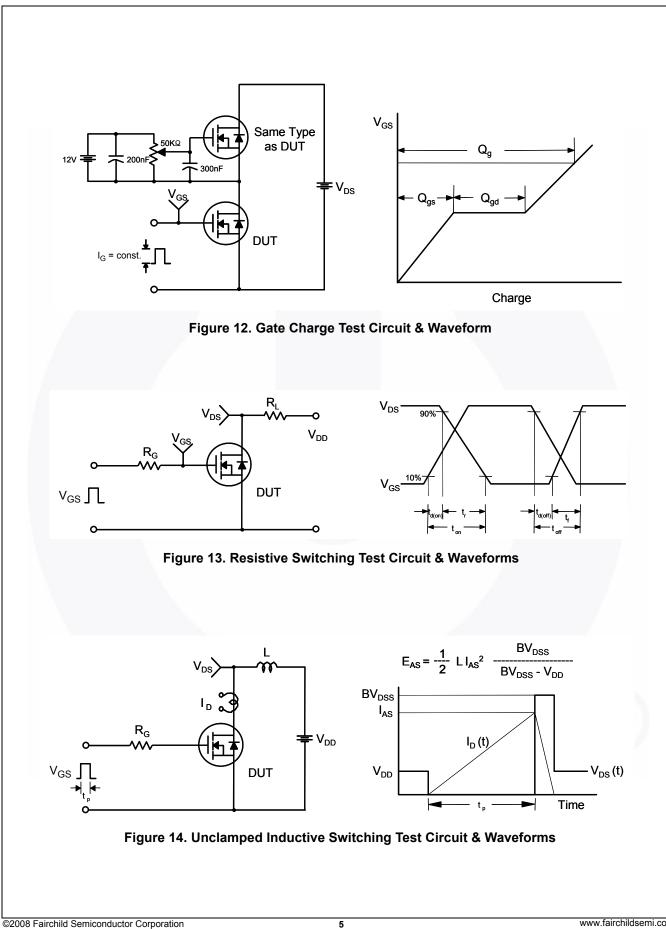
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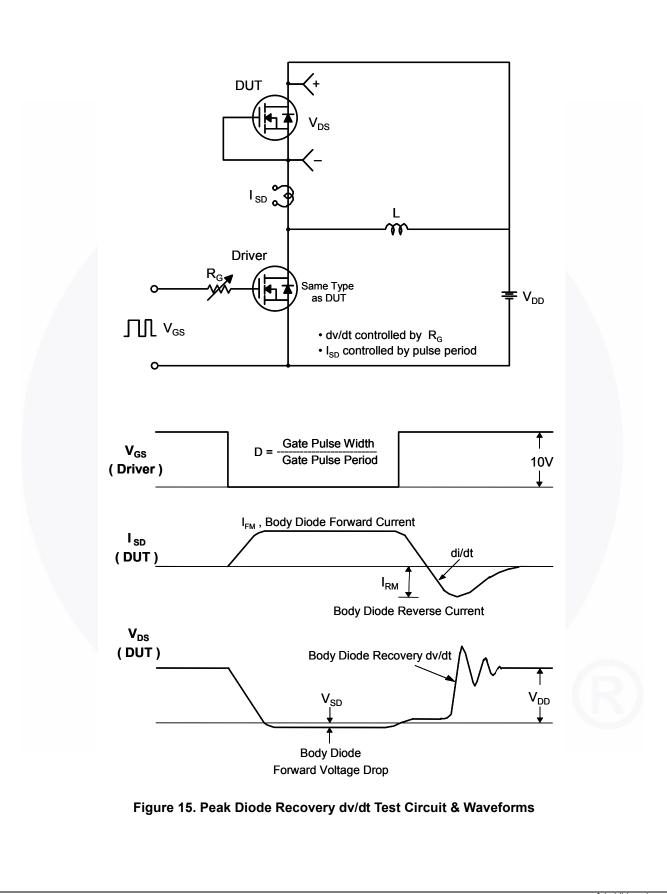


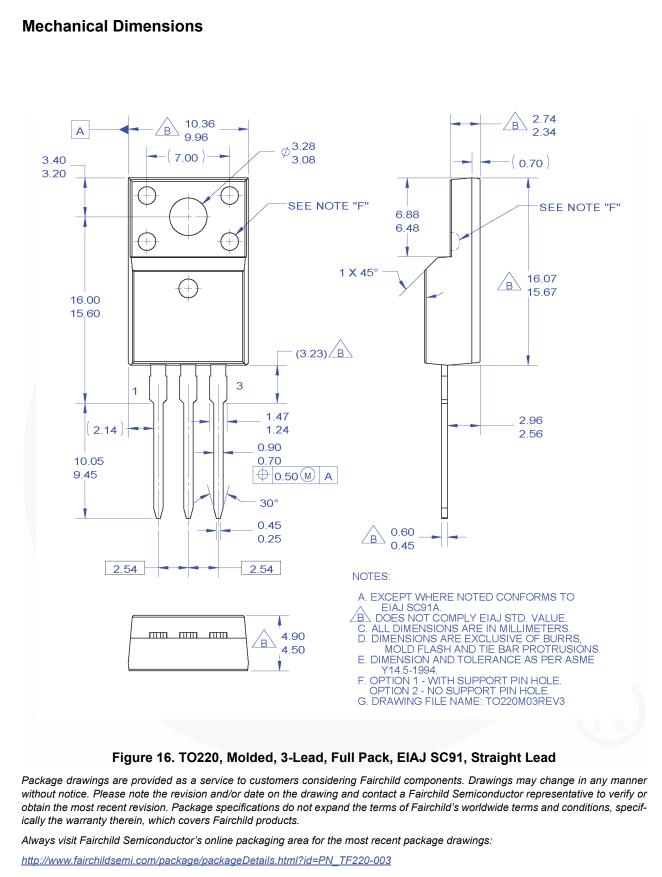
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